

NEW DRAWING SHEET

CREATING A WEAKENED ZONE IN A WAFER TO DEFINE THE LAYER TO BE DETACHED AND A REMAINDER PORTION OF THE WAFER SUCH THAT THE WEAKENED ZONE INCLUDES A MAIN REGION AND A LOCALIZED SUPER-WEAKENED REGION THAT IS MORE WEAKENED THAN THE MAIN REGION

INITIATING DETACHMENT OF THE LAYER FROM THE REMAINDER PORTION OF THE WAFER AT THE SUPER-WEAKENED REGION BY APPLYING A CONTROLLED DETACHMENT FORCE OBTAINED BY HEATING AT LEAST THE WEAKENED ZONE

FIGURE 4